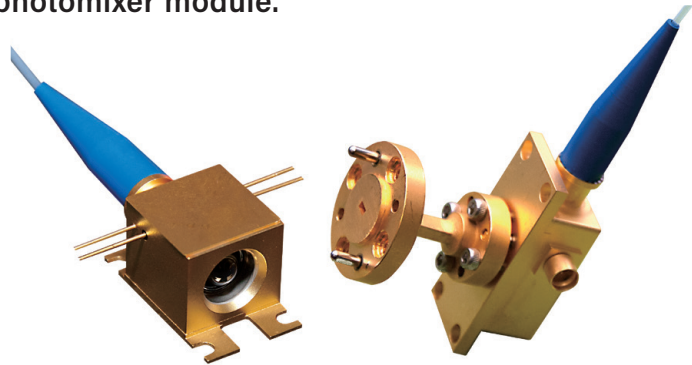


UTC Photomixer

Photonic generation of THz signals is promising for various applications. Especially important is that this technique can provide very wide bandwidths and low-loss transmission of very-high-frequency signals, which cannot be attained by current electronics-based techniques. For the development of a photonic THz generator system, 1550-nm photodiode having high output powers as well as superior high-frequency characteristics is a key component. The uni-travelling-carrier photodiode (UTC-PD) is one of the best solutions, because it provides a high 3 dB down bandwidth and high-saturation-output power simultaneously. NTT Innovative Devices have developed two types of UTC-PD photomixer modules. One is a compact rectangular-waveguide-coupled photomixer, and another is an antenna-integrated (quasi-optical module) photomixer module.

FEATURES

- Efficient THz generation
- Wide frequency-range operation
- High stability
- Room-temperature operation

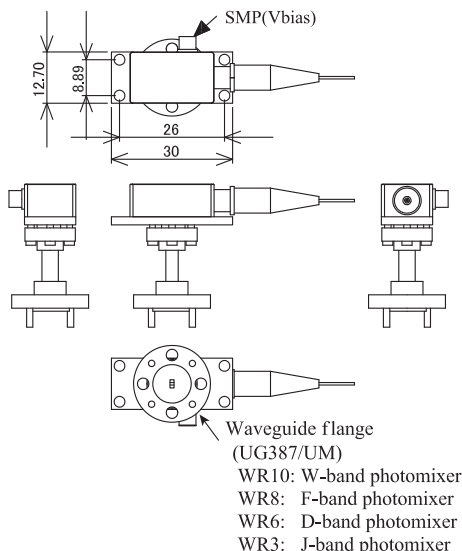


SPECIFICATIONS

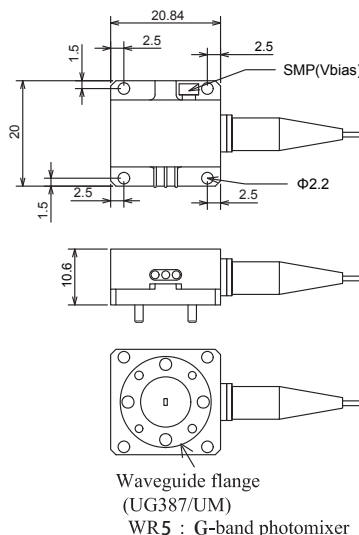
| Type | Model | Frequency (GHz) | | | Output power (dBm) | | |
|------|----------------|-----------------|------|--------|--------------------|-------|----------|
| | | Min. | Typ. | Max. | Min. | Max. | |
| W | IOD-PMW-13001 | 75 | 90 | 110 | -8.0 | -5.0 | @90GHz |
| | IOD-PMF-13001 | 90 | 115 | 140 | -8.0 | -5.0 | @140GHz |
| | IOD-PMD-14001 | 110 | 140 | 170 | -9.0 | -6.0 | @140GHz |
| | IOD-PMG-20001 | 140 | 180 | 220 | -18.0 | -11.0 | @180GHz |
| | IOD-PMJ-13001 | 280 | 330 | 380 | -18.0 | -11.0 | @330GHz |
| A | IOD-PMAN-13001 | 300 | | (3000) | -34.0 | -28.0 | @1000GHz |

OUTSIDE DIMENSIONS

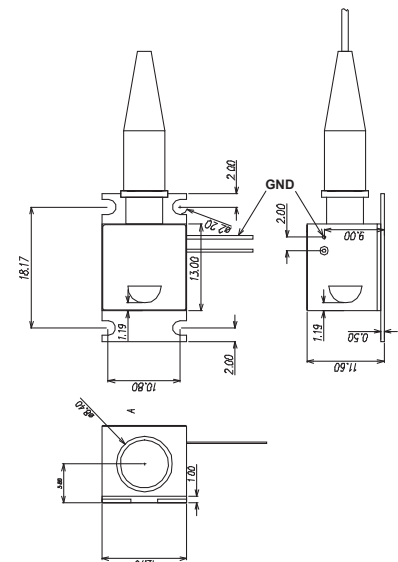
Rectangular-waveguide-coupled photomixer



G-band photomixer

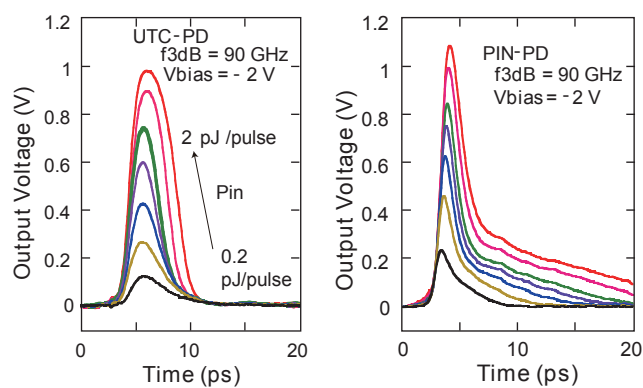


Antenna-integrated photomixer



KEY CONCEPTS OF UTC

UTC-PD was developed by NTT in Japan. A UTC diode features a moderately p-doped InGaAs absorption layer and a depleted, undoped or lightly n-doped InP carrier collection layer. Photocarriers are generated in the absorption layer. The electrons diffuse/drift into the (higher-bandgap) collection layer but, due to an additional diffusion block, not to the p-contact layer. The holes, by contrast, travel to the p-contact but do not enter the collection layer. Thus, only the electrons cross the collection layer. This type of carrier transport is substantially different from conventional p-i-n diodes, where both electrons and holes contribute to the high-frequency photocurrent.

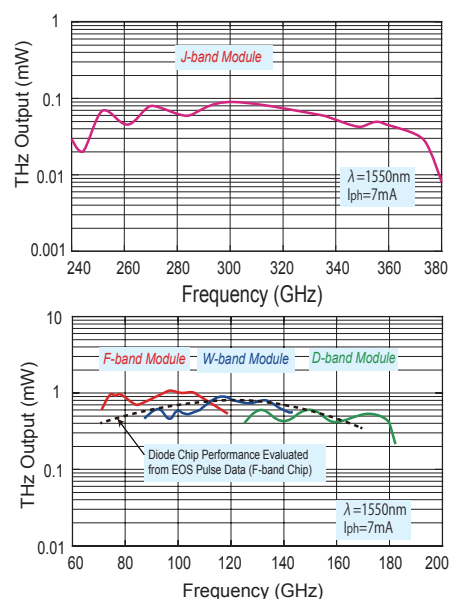
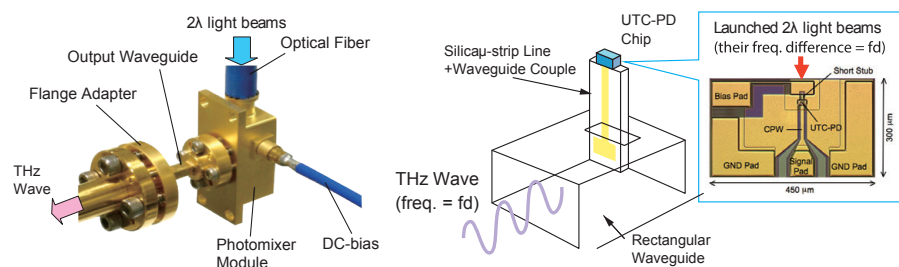


RECTANGULAR-WAVEGUIDE-COUPLED PHOTOMIXER

The photomixer module has a PD-waveguide mode-conversion coupler and output rectangular waveguide.

The coupler is fabricated on quartz substrate and acts as a circuit to match impedance between PD chip and the waveguide.

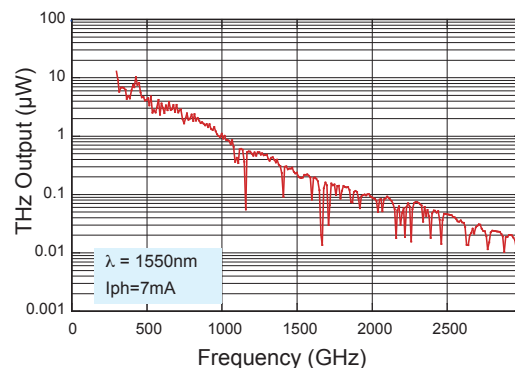
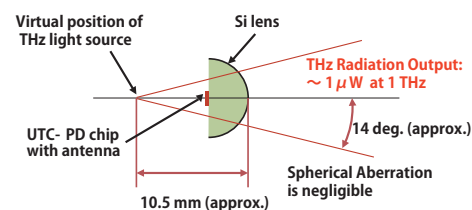
NTT Innovative Devices manufactures rectangular waveguide coupled photomixer with sub-THz frequency region below about 300 GHz.



ANTENNA-INTEGRATED PHOTOMIXER

A UTC-PD chip is monolithically integrated with a broad-band antenna (self-complementary bow-tie antenna). The chip was placed on a hyper-hemispherical Si lens and electrically connected to the dc bias leads. The THz wave was emitted through Si lens.

The output power decreased gradually with increasing frequency, and we could detect submillimeter waves at frequencies of up to 3 THz. The output power increased linearly in proportion to the square of the photocurrent. The typical output power was -30 dBm at 1 THz for a photocurrent of about 7 mA.



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Sensing application
website